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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/692,176	10/22/2003	James P. Siepmann	LTI.PAU.04	8354
7590 04/04/2007 Clark Caflisch		7	EXAMINER	
LightTime, Inc. 375 City Center			PHAN, HANH	
Suite N	•		ART UNIT	PAPER NUMBER
Oshkosh, WI 5	4901		2613	
				
SHORTENED STATUTORY PERIOD OF RESPONSE		MAIL DATE	DELIVERY MODE	
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Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

			← X
	Application No.	Applicant(s)	
	10/692,176	SIEPMANN, JAME	ES P.
Office Action Summary	Examiner	Art Unit	
	Hanh Phan	2613	
The MAILING DATE of this communication appeared for Reply	ppears on the cover s	heet with the correspondence ad	dress
A SHORTENED STATUTORY PERIOD FOR REP WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory perior - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS CON .136(a). In no event, howeve d will apply and will expire SIX tte, cause the application to be	IMUNICATION. If, may a reply be timely filed ((6) MONTHS from the mailing date of this concerned ABANDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 22	October 2003.		
2a) This action is FINAL . 2b) ☑ Th	is action is non-final.		
3) Since this application is in condition for allow	ance except for form	al matters, prosecution as to the	merits is
closed in accordance with the practice under	Ex parte Quayle, 19	35 C.D. 11, 453 O.G. 213.	
Disposition of Claims			
4) ☐ Claim(s) 1-20 is/are pending in the application 4a) Of the above claim(s) is/are withdr 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-17 is/are rejected. 7) ☐ Claim(s) 18-20 is/are objected to. 8) ☐ Claim(s) are subject to restriction and	awn from considerati	-	•
Application Papers			
9) The specification is objected to by the Examir 10) The drawing(s) filed on <u>22 October 2003</u> is/ar Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction.	re: a)⊠ accepted or e drawing(s) be held in	abeyance. See 37 CFR 1.85(a).	
11) The oath or declaration is objected to by the I	Examiner. Note the a	ttached Office Action or form PT	TO-152.
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreignal All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bure * See the attached detailed Office action for a list	nts have been receivents have been receive fority documents have au (PCT Rule 17.2(a	ed. ed in Application No e been received in this National)).	Stage
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	9a 5) <u> </u>	terview Summary (PTO-413) sper No(s)/Mail Date btice of Informal Patent Application ther:	

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-17 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hasson (US Patent No. 6,967,977).

Regarding claims 1, 9 and 17, referring to Figures 1A, 1B, 2, 3A, 3B and 4, Hasson teaches in an optoelectronic timing system, an adaptive frequency generator system comprising:

at least one semiconductor laser (i.e., laser source 11, Figs. 1A and 2) configured to issue optical pulses defining a periodic pulse train (i.e., col. 3, lines 12-67, col. 4, lines 1-67, col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50);

at least a first optical waveguide (i.e., Figs. 1A and 2), the waveguide configured to define a first time-quantifiable optical path for a pulse of the train (i.e., col. 3, lines 12-67, col. 4, lines 1-67, col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50);

at least one additional optical waveguide (i.e., Figs. 1A and 2), the additional waveguide configured to define a second time-quantifiable optical path for a pulse of the train different from the first waveguide (i.e., col. 3, lines 12-67, col. 4, lines 1-67, col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50);

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a first nodal point (i.e., Figs. 1A and 2) coupled to the first and second waveguides at which pulses of the train are directed into the first and second waveguides (i.e., col. 3, lines 12-67, col. 4, lines 1-67, col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50);

a second nodal point (i.e., Figs. 1A and 2) coupled to the first and second waveguides at which pulses directed into the first and second waveguides are recombined (i.e., col. 3, lines 12-67, col. 4, lines 1-67, col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50); and

wherein, the length of the second time-quantifiable optical path has a defined numerical relationship to the length of the first time-quantifiable optical path, such that the periodicity of pulses recombined at the second nodal point has the same numerical relationship with the periodicity of the issued pulse train (i.e., Figs.1A and 2, col. 3, lines 12-67, col. 4, lines 1-67, col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50).

Hasson differs from claims 1, 9 and 17 in that he does not specifically teach a laser configured to issue subnanosecond optical pulses defining a periodic pulse train. However, Hasson teaches that with the growing applicability of optical communications systems, particularly TDM systems, there has been a concurrent increase in demand for optical pulse generators capable of increasingly rapid repetition rates. Presently, optical pulse generators with repetition rates in the GigaHertz range are known (i.e., col. 1, lines 45-52). Therefore, it would have been obvious to obtain a laser configured to issue subnanosecond optical pulses defining a periodic pulse train in order to provide an optical pulse train generator with high repetition rate, since it has been held that where

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the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art. *In re A11er, 105 USPQ 233*.

Regarding claims 2 and 10, Hasson further teaches the at least one semiconductor laser is configured to provide a pulsed output having a periodicity in the range of about 1 nanosecond so as to define a 1 gigahertz pulse train (i.e., col. 1, lines 45-52).

Regarding claims 3, 7, 11 and 15, Hasson teaches all the aspects of the claimed invention as set forth in the rejection to claim 1 above except fails to specifically teach the second optical time-quantifiable optical path has a length differing from the first timequantifiable optical path by about 0.5 nanoseconds, so as to define a 2 gigahertz pulse train at the second nodal point or the lengths of the multiplicity of time-quantifiable optical paths differ from one another by about 0.2 nanoseconds, so as to define a 5 gigahertz pulse train at the second nodal point. However, Hasson teaches that the length of each step or the step-length facet, e.g., 16-1, may be tuned by the application of a tuning voltage. Additionally, in this way the delay structure 12 may be tuned to produce differing repetition rates for continuous trains or grouped series of subpulses (i.e., col. 7, lines 4-50). Therefore, it would have been obvious to obtain the second optical time-quantifiable optical path has a length differing from the first time-quantifiable optical path by about 0.5 nanoseconds, so as to define a 2 gigahertz pulse train at the second nodal point or the lengths of the multiplicity of time-quantifiable optical paths differ from one another by about 0.2 nanoseconds, so as to define a 5 gigahertz pulse train at the second nodal point in order to provide a higher optical timing frequency,

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since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art. *In re A11er, 105 USPQ 233.*

Regarding claims 4 and 12, Hasson teaches further comprising: a multiplicity of additional optical waveguides each coupled to the first and second nodal points, the additional waveguides configured to define a multiplicity of time-quantifiable optical paths; and wherein, the lengths of each of the multiplicity of additional time-quantifiable optical paths having a numerical relationship with each other and with the first time-quantifiable optical path (i.e., Figs.1A and 2, col. 3, lines 12-67, col. 4, lines 1-67 and col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50).

Regarding claims 5 and 13, Hasson further teaches the semiconductor laser is configured to provide a pulsed output at a first periodicity and wherein the recombined pulse train at the second nodal point provides a pulse train having a second periodicity, the second periodicity being a multiple of the first, the multiple defined by the numerical relationship between the multiplicity of additional time-quantifiable optical paths and the first time-quantifiable optical path (i.e., col. 4, lines 5-10 and col. 7, lines 4-50).

Regarding claims 6 and 14, Hasson further teaches the semiconductor laser operates at a frequency of about 1 gigahertz (i.e., col. 1, lines 45-52 and col. 4, lines 4-50).

Regarding claims 8 and 16, Hasson further teaches the time quantification of the optical path length is defined by the distance required for a pulse to travel at the speed

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of light for a given time interval (i.e., Figs.1A and 2, col. 3, lines 12-67, col. 4, lines 1-67 and col. 5, lines 1-44, col. 6, lines 32-67 and col. 7, lines 1-50).

Allowable Subject Matter

3. Claims 18-20 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Liedenbaum et al (US Patent No. 5,691,832) discloses coherent multiplexed transmission system.

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hanh Phan whose telephone number is (571)272-3035.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Jason Chan, can be reached on (571)272-3022. The fax phone number for the organization where this application or proceeding is assigned is (571)273-8300.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)305-4700.

HANH PHAN
PRIMARY EXAMINER